

isc N-Channel MOSFET Transistor

FMR19N60ES

• FEATURES

- · With TO-3PML packaging
- · Maintains both low power loss andlow noise
- · Very high commutation ruggedness
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operationz



APPLICATIONS

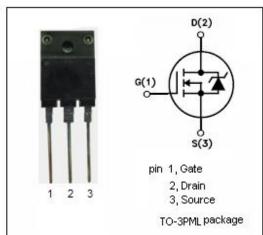
- Switching applications
- DC-DC converters
- Uninterruptible power supply

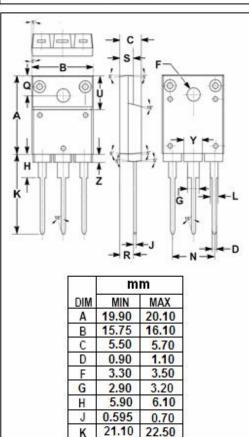
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	600	V
V _{GSS}	Gate-Source Voltage	rce Voltage ±30	
I _D	Drain Current-Continuous	19	А
I _{DM}	Drain Current-Single Pulsed	76	А
P _D	Total Dissipation	150	W
Tj	Operating Junction Temperature	-55~150	°C
T _{stg}	Storage Temperature	-55~150	$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.83	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W	





	15.50	20.10
В	15.75	16.10
С	5.50	5.70
D	0.90	1.10
F	3.30	3.50
G	2.90	3.20
Н	5.90	6.10
J	0.595	0.70
K	21.10	22.50
L	1.90	2.25
N	10.80	11.00
Q	4.90	5.10
R	3.75	3.95
S	3.20	3.60
U	9.90	10.10
Υ	4.20	4.90
Z	1.90	2.10



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	600			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =±30V; I _D =0.25mA	3.7		4.7	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =9.5A		310	365	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 600V; V _{GS} = 0V;Tc=25°C V _{DS} = 480V; V _{GS} = 0V;Tc=125°C			25 250	μА
V _{SDF}	Diode forward voltage	I _{SD} =19A, V _{GS} = 0 V			1.35	V

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